V6P22C

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High Current Density Surface-Mount TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.61$ V at $I_F = 1.5$ A

eSMP[®] Series



SMPC (TO-277A)

K → Anode 1 Cathode → Anode 2

ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 3.0 A			
V _{RRM}	200 V			
I _{FSM}	70 A			
V_F at $I_F = 3$ A	0.68 V			
T _J max.	175 °C			
Package	SMPC (TO-277A)			
Circuit configuration	Common cathode			

FEATURES

- Very low profile typical height of 1.1 mm
- Ideal for automated placement
- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

MECHANICAL DATA

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V6P22C	UNIT	
Device marking code		V622C		
Maximum repetitive peak reverse voltage	V _{RRM}	200	V	
Maximum average forward rectified current per device (fig. 1)	I _{F(AV)} ⁽¹⁾	6.0	— A	
	I _{F(AV)} ⁽²⁾	3.0		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	70	А	
Operating junction temperature range	T _J ⁽³⁾	-40 to +175	°C	
Storage temperature range	T _J , T _{STG}	-55 to +175	°C	

Notes

⁽¹⁾ Mounted on 30 mm x 30 mm pad areas aluminum PCB

⁽²⁾ Free air, mounted on recommended pad area

 $^{(3)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J < 1/R_{0JA}

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FREE

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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 1.5 A	T _A = 25 °C	V _E (1)	0.79	-	V
	I _F = 3.0 A			0.83	0.89	
	I _F = 1.5 A	T _A = 125 °C		VF ()	0.61 -	v
	I _F = 3.0 A			0.68	0.76	
Reverse current per diode	V _R = 160 V	T _A = 25 °C	I _R (2)	0.001	-	mA
		T _A = 125 °C		0.3	-	
	V _R = 200 V	T _A = 25 °C		-	0.06	
		T _A = 125 °C		0.7	3.5	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	130	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 $\,\%$ duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise specified)					
PARAMETER	SYMBOL V6P22C		UNIT		
Typical thermal resistance per device	R _{0JA} (1)(2)	85	°C/W		
	R _{0JM} ⁽³⁾	5	0/10		

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, mounted on recommended copper pad area, 2 oz., FR4 PCB, thermal resistance R_{0JA} - junction-to-ambient

⁽³⁾ Units mounted on 30 mm x 30 mm aluminum PCB, thermal resistance R_{0-JM} - junction-to-mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V6P22C-M3/H	0.10	Н	1500	7" diameter plastic tape and reel		
V6P22C-M3/I	0.10	I	6500	13" diameter plastic tape and reel		
V6P22CHM3/H ⁽¹⁾	0.10	Н	1500	7" diameter plastic tape and reel		
V6P22CHM3/I (1)	0.10	I	6500	13" diameter plastic tape and reel		

Note

⁽¹⁾ AEC-Q101 gualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

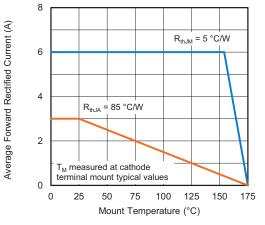


Fig. 1 - Maximum Forward Current Derating Curve

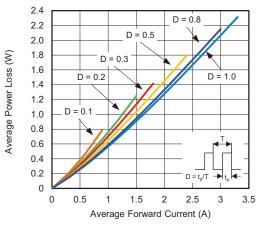
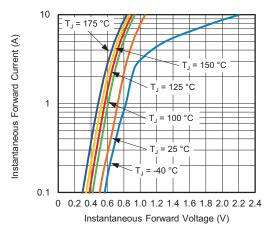
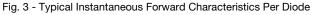


Fig. 2 - Forward Power Loss Characteristics Per Diode





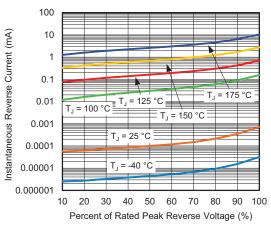


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

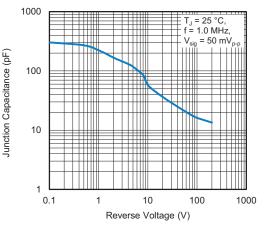
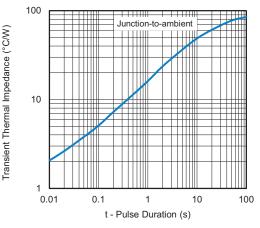


Fig. 5 - Typical Junction Capacitance Per Diode





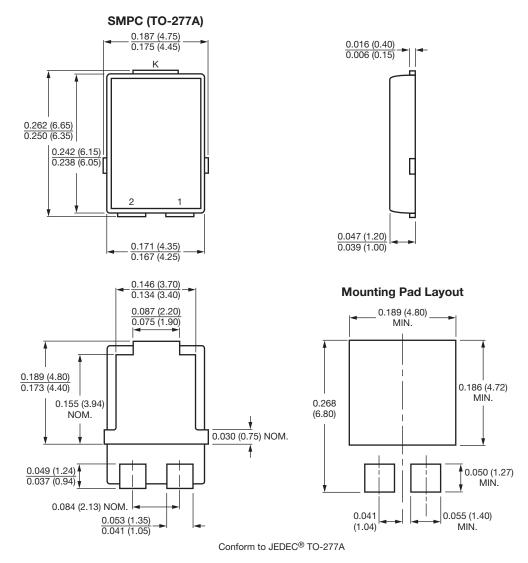
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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